

Technical Data Green Products

Data Sheet N1162, Rev. -

124NQ060/R-1 SCHOTTKY RECTIFIER

Applications:

• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

Features:

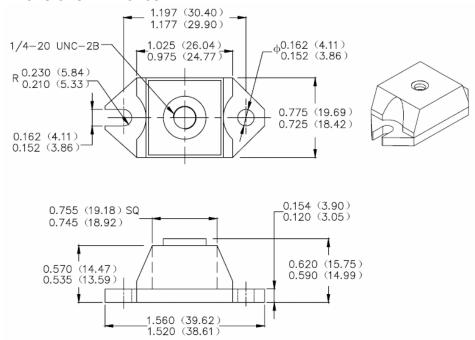
- 125°C T₁ operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5'S
- Easier to mount and lower profile than DO-5'S
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

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124NQ060-1

124NQ060R-1

Mechanical Dimensions: In Inches / mm



PRM1-1(HALF PAK Module)

MARKING, MOLDING RESIN

Marking for 124NQ060/R-1, 1st row SS YYWWL, 2nd row 124NQ060-1/124NQ060R-1 Where YY is the manufacture year WW is the manufacture week code L is the wafer's Lot Number Molding resin

Epoxy resin UL:94V-0

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Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units_
Peak Inverse Voltage	V_{RWM}	-	60	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =76°C, rectangular wave form	120	Α
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	2880	А
Non-Repetitive Avalanche Energy	E _{AS}	T _J =25℃,I _{AS} =20A,L=0.67mH	135	mJ
Repetitive Avalanche Current	I _{AR}	Current decaying linearly to zero in 1 μ sec Frequency limited by T_J max. V_A =1.5 \times V_R typical	20	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	V _{F1}	@ 120A, Pulse, T _J = 25 °C	0.54	V
		@ 240A, Pulse, T _J = 25 °C	0.71	
	V _{F2}	@ 120A, Pulse, T _J = 125 °C	0.52	\
		@ 240A, Pulse, T _J = 125 °C	0.71	
Max. Reverse Current (per	I _{R1}	$@V_R$ = rated V_R T_J = 25 °C	20	mA
leg) *	I _{R2}	$@V_R = \text{rated } V_R T_J = 125 ^{\circ}\text{C}$	6000	mA
Max. Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	5200	pF
Typical Series Inductance (per leg)	Ls	Measured lead to lead 5 mm from package body	7.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

Pulse Width < 300µs, Duty Cycle <2%

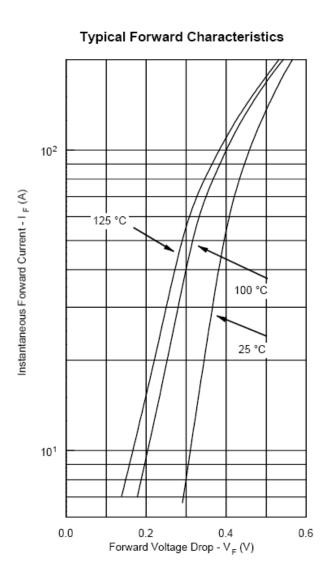
Thermal-Mechanical Specifications:

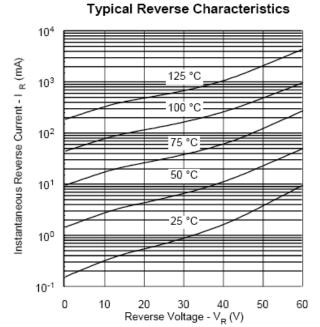
Characteristics	Symbol	Condition	Specification		Units	
Max. Junction Temperature	TJ	-	-55 to +125		°C	
Max. Storage Temperature	T _{stg}	-	-55 to +125		°C	
Maximum Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	0.40		°C/W	
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.15		°C/W	
Mounting Torque	Тм	Non-lubricated threads	Mounting Torque Terminal Torque	23(min) 29(max) 35(min) 46(max)	Kg-cm	
Approximate Weight	wt	-	25.6		g	
Case Style	PRM1-1					

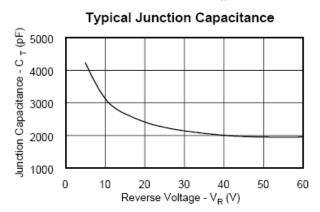
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